

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q66212

HIROYUKI, KIYOKU, et al.

Appln. No.: 09/986,332

Group Art Unit: 1765

Confirmation No.: 5542

Examiner: Anderson, Matthew A.

Filed: November 8, 2001

For:

NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR

SUBSTRATE, AND NITRIDE SEMICONDUCTOR DEVICE

EXCESS CLAIM FEE PAYMENT LETTER

Commissioner for Patents Washington, D.C. 20231

Sir:

An Amendment Under 37 C.F.R. § 1.111 is attached hereto for concurrent filing in the above-identified application. The resulting excess claim fee has been calculated as shown below:

	After Amendment	Highest No. Previously Paid For						
All Claims	, 46	- 27	=	19	X	\$18.00	=	\$342.00
Independent	4	- 4	=		x	\$84.00	_	\$.00
				ТОТ	AL		=	\$342.00

A check for the statutory fee of \$342.00 is attached. The USPTO is directed and authorized to charge all required fees, except for the Issue Fee and the Publication Fee, to Deposit Account No. 19-4880. Please also credit any overpayments to said Deposit Account. A duplicate copy of this letter is enclosed.

Respectfully submitted,

SUGHRUE MION, PLLC

2100 Pennsylvania Avenue, N.W.

David A. Klein

Registration No. 46,835

2100 Pennsylvania Avenue, N.W. Washington, D.C. 20037-3213

Telephone: (202) 293-7060 Facsimile: (202) 293-7860

Date: September 25, 2002